RENESAS

HD74LS95B 4-bit Parallel Access Shift Register

REJ03D0424-0400 Rev.4.00 May 10, 2006

The 4-bit register features parallel and serial inputs, parallel outputs, mode control, and two clock inputs. The register has three mode operation:

- Parallel (broadside) load
- Shift right (the direction Q_A toward Q_D)
- Shift left (the direction Q_D toward Q_A)

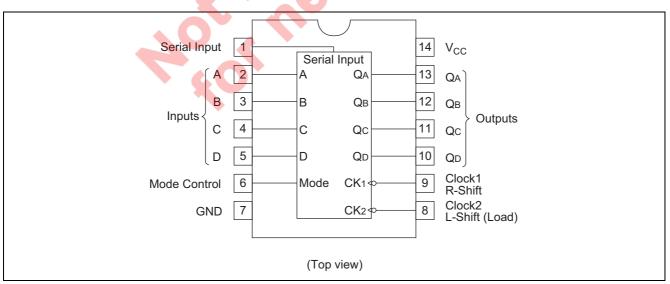
Parallel loading is accomplished by applying the four bits of data and taking the mode control input high. The data is loaded into the associated flip-flops and appears at the outputs after the high-to-low transition of the clock-2 input. During loading, the entry of serial data is inhibited. Shift right is accomplished on the high-to-low transition of clock-1 when the mode control is low; shift left is accomplished on the high-to-low transition of clock-2 when the mode control is high by connecting the output of each flip-flop to the parallel input of the previous flip-flop (Q_D to input C, etc.) and serial data is entered at input D. The clock input may be applied commonly to clock-1 and clock-2 if both modes can be clocked from the same source. Changes at the mode control inputs are low; however, conditions described in the last three lines of the function table will also ensure that register contents are protected.

Features

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS95BFPEL	SOP-14 pin (JEITA)	PRSP0014DF-B (FP-14DAV)	FP	EL (2,000 pcs/reel)

Pin Arrangement



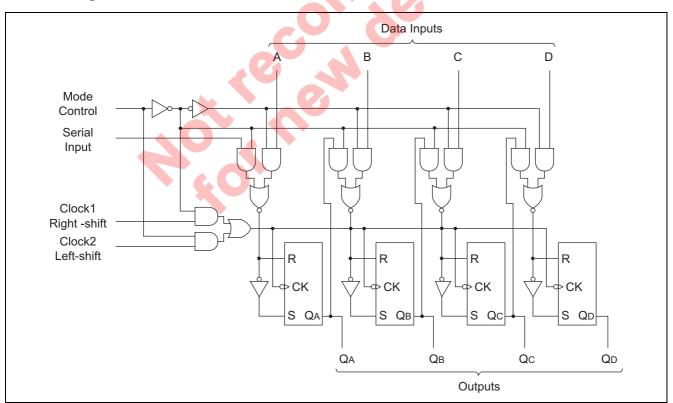


Function Table

			Inpu	ıts					Out	outs	
Mode	Clo	cks	Serial	Parallel		Q _A	0	0	•		
control	2(L)	1(R)	Serial	Α	В	С	D	QA	Q B	Q _C	QD
Н	Н	Х	Х	Х	Х	Х	Х	Q _{AO}	Q_{BO}	Q _{CO}	Q _{DO}
Н	\downarrow	Х	Х	а	b	С	d	а	b	С	d
Н	\downarrow	Х	Х	Q _B *	Q _C *	Q _D *	d	Q _{Bn}	Q _{Cn}	Q_Dn	d
L	L	Н	Х	Х	Х	Х	Х	Q _{AO}	Q _{BO}	Q _{CO}	Q _{DO}
L	Х	\downarrow	Н	Х	Х	Х	Х	Н	Q _{An}	Q _{Bn}	Q _{Cn}
L	Х	\downarrow	L	Х	Х	Х	Х	L	Q _{An}	Q _{Bn}	Q _{Cn}
\uparrow	L	L	Х	Х	Х	Х	Х	Q _{AO}	Q _{BO}	Q _{CO}	Q _{DO}
\downarrow	L	L	Х	Х	Х	Х	Х	Q _{AO}	Q _{BO}	Q _{CO}	Q _{DO}
\downarrow	L	Н	Х	Х	Х	Х	Х	Q _{AO}	Q _{BO}	Q _{CO}	Q _{DO}
\uparrow	Н	L	Х	Х	Х	Х	Х	Q _{AO}	Q _{BO}	Q _{CO}	Q _{DO}
\uparrow	Н	Н	Х	Х	Х	Х	Х	Q _{AO}	Q _{BO}	Q _{CO}	Q _{DO}

Notes: 1. H; high level, L; low level, X; irrelevant

- 2. \uparrow ; transition from low to high level
- 3. \downarrow ; transition from high to low level
- 4. a to d; the level of steady-state input at inputs A, B, C, or D, respectively.
- 5. Q_{AO} to Q_{DO}; the level of Q_A, Q_B, Q_C, or Q_D, respectively, before the indicated steady-state input conditions were established.
- 6. Q_{An} to Q_{Dn} ; the level of Q_A , Q_B , Q_C , or Q_D , respectively, before the most-recent (1) transition of the clock.
- 7. *; Shifting left require external connection of Q_B to A, Q_C to B, and Q_D to C. Serial data is entered at input D.



Block Diagram



Absolute Maximum Ratings

ltem	Symbol	Ratings	Unit
Supply voltage	V _{CC}	7	V
Input voltage	V _{IN}	7	V
Power dissipation	PT	400	mW
Storage temperature	Tstg	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

Recommended Operating Conditions

Item	Symbol	Min	Тур	Max	Unit			
Supply voltage	V _{CC}	4.75	5.00	5.25	V			
Output current	I _{OH}	—	—	-400	μA			
	I _{OL}	—	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	mA				
Operating temperature	Topr	-20	25	75	°C			
Clock frequency	f _{clock}	0	—	25	MHz			
Clock pulse width	t _{w (СК)}	20	-	—	ns			
Setup time	t _{su}	20		—	ns			
Hold time	t _h	10		_	ns			
Enable time 1	t _{enable 1}	20	—		ns			
Enable time 2	t _{enable 2}	20		-	ns			
Inhibit time 1	t _{inhibit 1}	20		—	ns			
Inhibit time 2	t _{inhibit 2}	20		—	ns			
Electrical Characteristics (Ta = -20 to +75 °C)								

Electrical Characteristics

Item	Symbol	min.	typ.*	max.	Unit	Condition
Input voltage	V _{IH}	2.0			V	
input voltage	V _{IL}		-	0.8	V	
	V _{OH}	2.7	_0		V	$V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V}, V_{IL} = 0.8 \text{ V},$
Output voltage	VOH	2.1			v	I _{OH} = -400 μA
	V _{OL}	—		0.4	v	$I_{OL} = 4 \text{ mA} \qquad V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V},$
				0.5	v	$I_{OL} = 8 \text{ mA}$ $V_{IL} = 0.8 \text{ V}$
	Η		—	20	μA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 2.7 \text{ V}$
Input current		P	—	-0.4	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 0.4 \text{ V}$
	lı 🗮	I	—	0.1	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 7 \text{ V}$
Short-circuit output	lee	-20		-100	mA	V _{CC} = 5.25 V
current	I _{OS}	-20		-100		V _{CC} = 5.25 V
Supply current**	I _{CC}	_	13	21	mA	V _{CC} = 5.25 V
Input clamp voltage	VIK	_	_	-1.5	V	$V_{CC} = 4.75 \text{ V}, I_{IN} = -18 \text{ mA}$

Notes: * $V_{CC} = 5 V$, Ta = 25°C

** I_{CC} is measured with all outputs and serial input open; A, B, C, and D inputs grounded; mode control at 4.5 V; and momentary 3 V, then ground, applied both clock inputs.

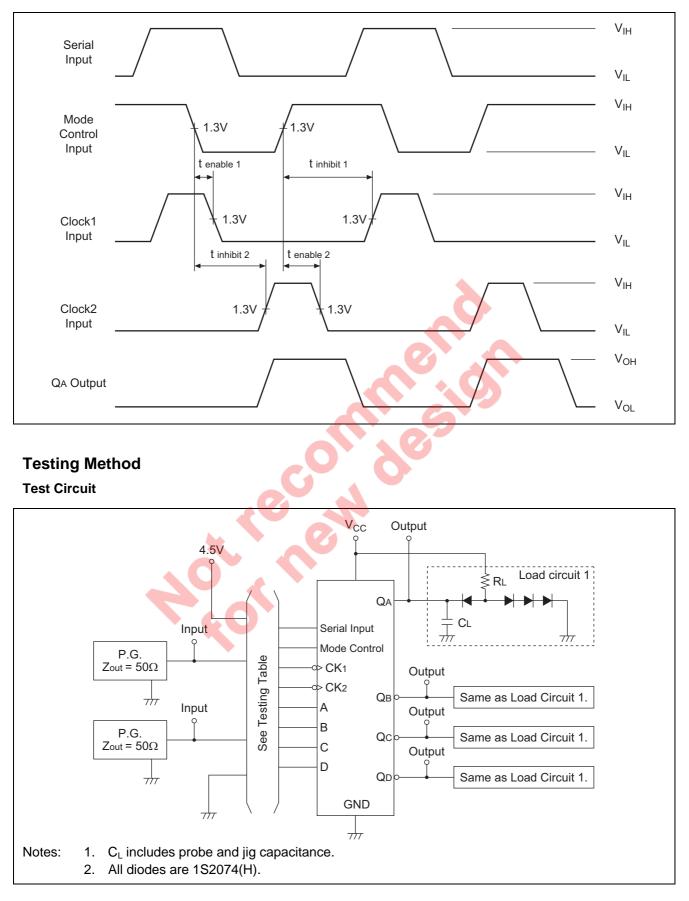
Switching Characteristics

$(V_{CC} =$	5	V,	Ta	=	25°	C)

ltem	Symbol	min.	typ.	max.	Unit	Condition
Maximum clock frequency	f _{max}	25	36	_	MHz	
Propagation delay time	t _{PLH}	—	18	27	ns	C_L = 15 pF, R_L = 2 k Ω
	t _{PHL}	_	21	32	ns	



Clock Enable / Inhibit Times



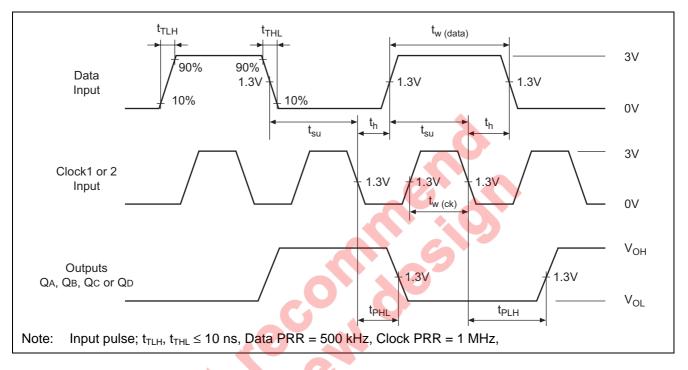


HD74LS95B

Testing Table

	From		Inputs									Outputs					
ltem	input to output	CK-1	CK-2	Mode control	Serial Inputs	Α	В	С	D	\mathbf{Q}_{A}	Q_{B}	Qc	\mathbf{Q}_{D}				
f _{max}	$CK-1 \rightarrow Q$	IN	4.5 V	0 V	IN	4.5 V	4.5 V	4.5 V	4.5 V	OUT	OUT	OUT	OUT				
Imax	$CK-2 \rightarrow Q$	4.5 V	IN	4.5 V	4.5 V	IN	IN	IN	IN	OUT	OUT	OUT	OUT				
t _{PLH}	$CK-1 \rightarrow Q$	IN	4.5 V	0 V	IN	4.5 V	4.5 V	4.5 V	4.5 V	OUT	OUT	OUT	OUT				
t _{PHL}	$CK-2 \rightarrow Q$	4.5 V	IN	4.5 V	4.5 V	IN	IN	IN	IN	OUT	OUT	OUT	OUT				

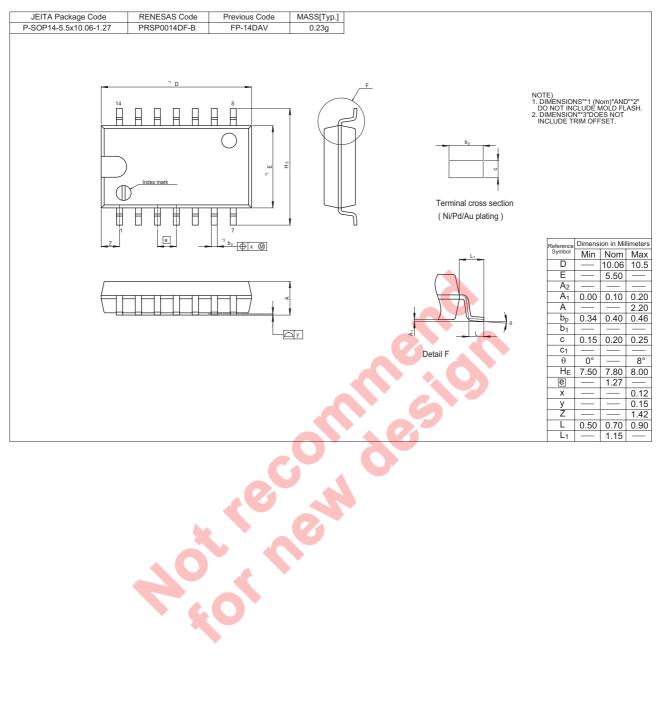
Waveform



200



Package Dimensions





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